\title{



## Features

- Ultralow ON resistance. - 2.5 V drive.

Package Dimensions

## Specifications

## Absolute Maximum Ratings at $\mathrm{Ta}=25^{\circ} \mathrm{C}$

| Parameter |  | Ratings | Unit |
| :---: | :---: | :---: | :---: |
| Drain-to-Source Voltage |  | 20 | V |
| Gate-to-Source Voltage | VGSS | $\pm 10$ | V |
| Drain Current (DC) |  | 14 | A |
| Drain Current (pulse) |  | 52 | A |
| Allowable Power Dissipation |  | 2.0 | W |
| Channel Temperature | Tob He | 150 | C |
| Storage Temperature | Fsto ${ }^{\text {a }}$ | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |

Electrical Characteristics at $\mathrm{fa}=25 \mathrm{Cm}$

| Parameter |  | Conditions | Ratings |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | min | typ | max |  |
| Drain-to-Source Breakdown Voltage en | $V$ (BR)DSS | $\mathrm{D}=\mathrm{F} \mathrm{mA}, \mathrm{V}_{\mathrm{GS}}=0$ | 20 |  |  | V |
| Zero-Gate Voltage Drain Cufrent | IbSS | $V_{\text {DS }}=20 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0$ |  |  | 1 | $\mu \mathrm{A}$ |
| Gate-to-Source Leakage Current | IGSS ${ }^{\text {fi }}$ | $\mathrm{V}_{\mathrm{GS}}= \pm 8 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0$ |  |  | $\pm 10$ | $\mu \mathrm{A}$ |
| Cutoff Voltage Fi \% \% | $\mathrm{V}_{\mathrm{GS}}(\mathrm{fff})^{\text {a }}$ | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=1 \mathrm{~mA}$ | 0.4 |  | 1.3 | V |
| Forward Transfer Admiffance | \%isid | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=14 \mathrm{~A}$ | 30 | 45 |  | S |
|  | FDSS(on) ${ }^{1}$ | $\mathrm{I}_{\mathrm{D}}=14 \mathrm{~A}, \mathrm{~V}_{\mathrm{GS}}=4 \mathrm{~V}$ |  | 6.5 | 9 | $\mathrm{m} \Omega$ |
| Static Drain-to-gy | RDS(on) ${ }^{2}$ | $\mathrm{I}_{\mathrm{D}}=7 \mathrm{~A}, \mathrm{~V}_{\mathrm{GS}}=2.5 \mathrm{~V}$ |  | 9 | 12 | $\mathrm{m} \Omega$ |
| Input Capacitape , , \% , \% | Fi' Ciss | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 5100 |  | pF |
| Output Capaếtance wry | Coss | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 1400 |  | pF |
| Reverse Transfer Gapatanoesy | Crss | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 950 |  | pF |


-Any and all SANYO products described or contained herein do not have specifications that can handle appliçations thát require extremely high levels of reliability, such as life-support systems, aircraft's control"systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.

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Continued from preceding page.

| Parameter | Symbol | Conditions | Ratings |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | min | typ | max |  |
| Turn-ON Delay Time | $\mathrm{t}_{\mathrm{d}(\mathrm{on})}$ | See specified Test Circuit |  | 60 |  | ns |
| Rise Time | $\mathrm{t}_{\mathrm{r}}$ | See specified Test Circuit |  | 750 |  | ns |
| Turn-OFF Delay Time | $\mathrm{t}_{\mathrm{d} \text { (off) }}$ | See specified Test Circuit |  | 470 |  | ns |
| Fall Time | $\mathrm{t}_{\mathrm{f}}$ | See specified Test Circuit |  | 640 |  | ns |
| Total Gate Charge | Qg | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=14 \mathrm{~A}$ |  | 1160 |  | nC |
| Gate-to-Source Charge | Qgs | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=14 \mathrm{~A}$ |  | 9.4 |  | nC |
| Gate-to-Drain "Miller" Charge | Qgd | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=14 \mathrm{~A}$ |  | 24.8 |  | *nC |
| Diode Forward Voltage | $\mathrm{V}_{\text {SD }}$ | $\mathrm{I}_{\mathrm{S}}=14 \mathrm{~A}, \mathrm{~V}_{\mathrm{GS}}=0$ |  | + 0,8 | 1.2 | V |

## Switching Time Test Circuit





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